

### Octal channel high-side driver

#### Datasheet - production data



#### **Features**

Туре	R <sub>DS(on)</sub> <sup>(1)</sup>	I <sub>OUT</sub>	V <sub>CC</sub>
VN808-E	150 m $\Omega$	0.7 A	45 V

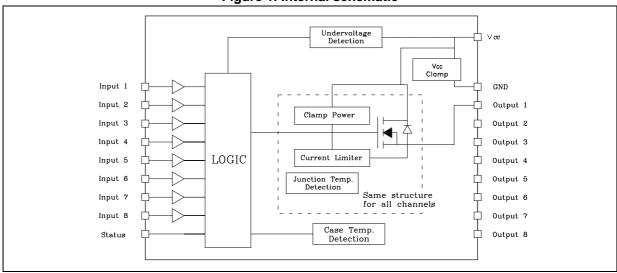
- 1. Per channel
- V<sub>CC</sub>/2 compatible input
- Junction overtemperature protection
- Case overtemperature protection for thermal independence of the channels
- Current limitation
- Short-circuit load protection
- Undervoltage shutdown

- · Protection against loss of ground
- · Very low standby current
- Compliance to 61000-4-4 IEC test up to 4 kV

#### **Description**

The VN808-E is a monolithic device, realized in STMicroelectronics VIPower M0-3 technology, intended to drive any kind of load with one side connected to ground. Active current limitation combined with thermal shutdown and automatic restart, protect the device against overload. In overload conditions, the channel turns OFF and ON again automatically in order to maintain the junction temperature between T<sub>TSD</sub> and T<sub>R</sub>. If this condition makes case temperature reach T<sub>CSD</sub>, overloaded channels are turned OFF and restart only when case temperature decreases down to T<sub>CR</sub>. Non-overloaded channels continue to operate normally. The device automatically turns OFF in case of ground pin disconnection. This device is especially suitable for industrial applications conform to IEC 61131.

Figure 1. Internal schematic



Contents VN808-E

## **Contents**

9	Revi	sion history
8	Orde	ring information
	7.3	Tape and reel shipment information
	7.2	Tube shipment information
	7.1	Footprint recommended data
7	Pack	age mechanical data
6	Reve	rse polarity protection13
5	Swite	ching time waveforms10
4	Curr	ent, voltage conventions and internal diagram 8
3	Pin c	onnections
2	Elect	rical characteristics4
1	Maxi	mum ratings

VN808-E Maximum ratings

# 1 Maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC supply voltage	45	V
-I <sub>GND</sub>	DC ground reverse current TRAN ground reverse current (pulse duration < 1 ms)	-250 -6	mA A
I <sub>OUT</sub>	DC output current	Internally limited	Α
-l <sub>OUT</sub>	Reverse DC output current	-2	Α
I <sub>IN</sub>	DC input current	± 10	mA
V <sub>IN</sub>	Input voltage range	-3/+V <sub>CC</sub>	V
V <sub>ESD</sub>	Electrostatic discharge (R = 1.5 kΩ; C = 100 pF)	2000	V
P <sub>TOT</sub>	Power dissipation at T <sub>C</sub> = 25 °C	96	W
EAS	Single pulse avalanche energy per channel 8 channels driven simultaneously (T <sub>AMB</sub> = 125 °C, I <sub>OUT</sub> = 0.6 A per channel)	1.15	J
TJ	Junction operating temperature	Internally limited	°C
T <sub>C</sub>	Case operating temperature	Internally limited	°C
T <sub>STG</sub>	Storage temperature	-40 to 150	°C

Table 2. Thermal data

Symbol	Parameter		Value	Unit
$R_{th(JC)}$	Thermal resistance junction-case	Max.	1.3	°C/W
R <sub>th(JA)</sub>	Thermal resistance junction-ambient <sup>(1)</sup>	Max.	50	°C/W

When mounted on FR4 printed circuit board with 0.5 cm<sup>2</sup> of copper area (at least 35 μm think) connected to all TAB pins.

Electrical characteristics VN808-E

### 2 Electrical characteristics

4/22

10.5 V <  $V_{CC}$  < 32 V; - 40 °C <  $T_{J}$  < 125 °C; unless otherwise specified.

**Table 3. Power section** 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>CC</sub>	Operating supply voltage		10.5		45	V
V <sub>USD</sub>	Undervoltage shutdown		7		10.5	V
R <sub>ON</sub>	On-state resistance	I <sub>OUT</sub> = 0.5 A; T <sub>J</sub> = 25 °C I <sub>OUT</sub> = 0.5 A; T <sub>J</sub> = 125 °C		150	185 280	mΩ
I <sub>S</sub>	Supply current	Off-state; V <sub>CC</sub> = 24 V; T <sub>CASE</sub> = 25 °C On-state (all channels ON); V <sub>CC</sub> = 24 V, T <sub>CASE</sub> = 100 °C			150 12	μA mA
I <sub>LGND</sub>	Output current at turn-off	$V_{CC} = V_{STAT} = V_{IN} = V_{GND} = 24 \text{ V}$ $V_{OUT} = 0 \text{ V}$			1	mA
I <sub>L(off)</sub>	Off-state output current	$V_{IN} = V_{OUT} = 0 V_{;}$	0		5	μА
V <sub>OUT(off)</sub>	Off-state output voltage	V <sub>IN</sub> = 0 V <sub>,</sub> I <sub>OUT</sub> = 0 A			3	V
t <sub>d(Vccon)</sub>	Power-on delay time from V <sub>CC</sub> rising edge	Figure 7 on page 10		1		ms

Table 4. Switching  $(V_{CC} = 24 V)$ 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>ON</sub>	Turn-on time	$R_L = 48 \Omega \text{ from } 80\% \text{ V}_{OUT}$ (see <i>Figure 6</i> )	-	50	100	μs
t <sub>OFF</sub>	Turn-off time	$R_L = 48 \Omega \text{ to } 10\% \text{ V}_{OUT}$ (see <i>Figure 6</i> )	-	75	150	μs
dVOUT/dt(on)	Turn-on voltage slope	$R_L = 48 \Omega$ from $V_{OUT} = 2.4 V$ to $V_{OUT} = 19.2 V$ (see <i>Figure 6</i> )	-	0.7		V/µs
dVOUT/dt(off)	Turn-off voltage slope	$R_L = 48 \Omega \text{ from } V_{OUT} = 21.6 \text{ V to}$ $V_{OUT} = 2.4 \text{ V (see } Figure 6)$	-	1.5		V/µs

Table 5. Input pin

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>INL</sub>	Input low level				V <sub>CC</sub> /2-1	V
I <sub>INL</sub>	Low level input current	V <sub>IN</sub> = V <sub>CC</sub> / 2 - 1 V	80		650	μΑ
V <sub>INH</sub>	Input high level		V <sub>CC</sub> /2+1			V
I <sub>INH</sub>	High level input current	V <sub>IN</sub> = V <sub>CC</sub> / 2 + 1 V		150	260	μΑ
V <sub>I(HYST)</sub>	Input hysteresis voltage			0.6		V
I <sub>IN</sub>	Input current	V <sub>IN</sub> = V <sub>CC</sub> = 32 V			300	μΑ

#### **Table 6. Protection**

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
T <sub>CSD</sub>	Case shutdown temperature		125	130	135	°C
T <sub>CR</sub>	Case reset temperature		110			°C
T <sub>CHYST</sub>	Case thermal hysteresis		7	15		°C
T <sub>TSD</sub>	Junction shutdown temperature		150	175	200	°C
T <sub>R</sub>	Junction reset temperature		135			°C
T <sub>HYST</sub>	Junction thermal hysteresis		7	15		°C
I <sub>lim</sub>	DC short-circuit current per channel	$V_{CC} = 24 \text{ V}; R_{LOAD} = 10 \text{ m}\Omega$	0.7		1.7	Α
V <sub>demag</sub>	Turn-off output clamp voltage	I <sub>OUT</sub> = 0.5 A; L = 6 mH	V <sub>CC</sub> -57	V <sub>CC</sub> -52	V <sub>CC</sub> -47	V

#### Table 7. Status pin

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>HSTAT</sub>	High level output current	$V_{CC}$ = 1832 V; R <sub>STAT</sub> = 1 kΩ (Fault condition)	2	3	4	mA
I <sub>LSTAT</sub>	Leakage current	Normal operation; V <sub>CC</sub> = 32 V			0.1	μΑ
V <sub>CLSTAT</sub>	Clamp voltage	I <sub>STAT</sub> = 1 mA I <sub>STAT</sub> = -1 mA	6.0	6.8 -0.7	8.0	V V

Pin connections VN808-E

### 3 Pin connections

V<sub>CC</sub> N.C. N.C. OUTPUT 1 OUTPUT 1 OUTPUT 2 N.C. OUTPUT 2 OUTPUT 3 N.C. INPUT 1 OUTPUT 3 OUTPUT 4 INPUT 2 INPUT 3 OUTPUT 4 INPUT 4 OUTPUT 5 INPUT 5 OUTPUT 5 INPUT 6 OUTPUT 6 INPUT 7 OUTPUT 6 INPUT 8 OUTPUT 7 OUTPUT 7 N.C. N.C. OUTPUT 8 OUTPUT 8 N.C. N.C. STATUS N.C. GND 、 V<sub>CC</sub>

Figure 2. Connection diagram (top view)

**Table 8. Pin functions** 

	Dir. Oranbal Franction					
Pin	Symbol	Function				
TAB	V <sub>CC</sub>	Positive power supply voltage				
1	V <sub>CC</sub>	Positive power supply voltage				
2,3,4,5	NC	Not connected				
6	Input 1	Input of channel 1				
7	Input 2	Input of channel 2				
8	Input 3	Input of channel 3				
9	Input 4	Input of channel 4				
10	Input 5	Input of channel 5				
11	Input 6	Input of channel 6				
12	Input 7	Input of channel 7				
13	Input 8	Input of channel 8				
14,15,16,17,18	NC	Not connected				
19	GND	Logic ground				
20	STATUS	Common open source diagnostic for overtemperature				
21,22	Output 8	High-side output of channel 8				
23,24	Output 7	High-side output of channel 7				
25, 26	Output 6	High-side output of channel 6				

VN808-E Pin connections

Table 8. Pin functions (continued)

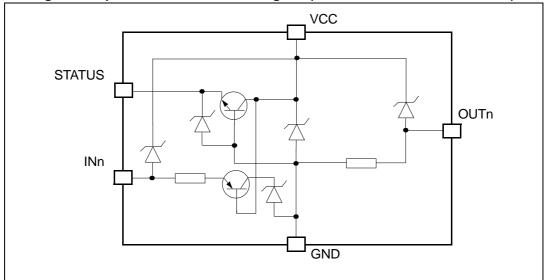
Pin	Symbol	Function
27. 28	Output 5	High-side output of channel 5
29, 30	Output 4	High-side output of channel 4
31, 32	Output 3	High-side output of channel 3
33, 34	Output 2	High-side output of channel 2
35, 36	Output 1	High-side output of channel 1

## 4 Current, voltage conventions and internal diagram

INPUTN OUTPUTN Voutn Vou

Figure 3. Current and voltage conventions





8/22 DocID11455 Rev 12

Filter for bus inductance effect, make supply voltage stable and avoid undervoltage shut down

EMC Filter

Protection for IEC 61000-4-5

Surge test

Vcc

Vcc

Vin2

Vin3

Vin8

Vin8

Vin8

Vin8

Frotection against IEC 61000-4-6

Current injection test

AM16519v1

Figure 5. Application example

Table 9. Truth table

Conditions	INPUTn	OUTPUTn	STATUS
Normal operation	L	L	L
	H	H	L
Current limitation	L	L	L
	H	X	L
Overtemperature (see waveforms 3, 4 <i>Figure 8</i> ) -> T <sub>J</sub> > T <sub>TSD</sub>	L	L	L
	H	L	H
Undervoltage	L H	L	X X



# 5 Switching time waveforms

Figure 6. Turn-ON and turn-OFF

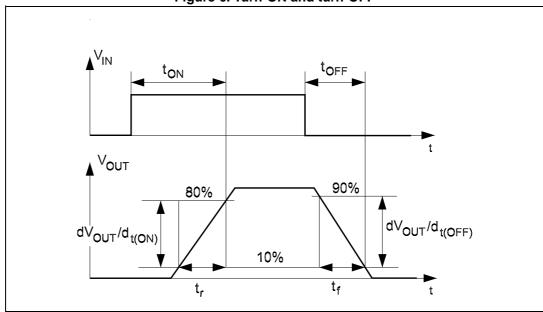


Figure 7. V<sub>CC</sub> turn-ON

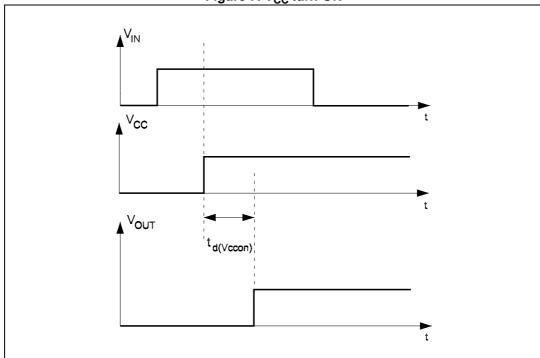
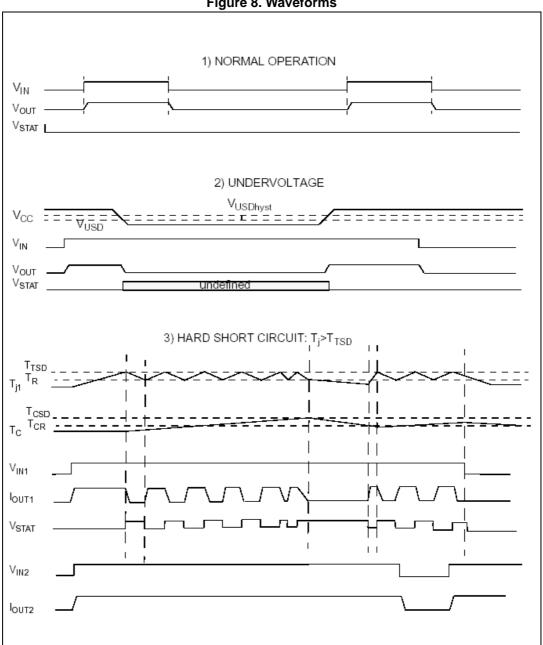


Figure 8. Waveforms



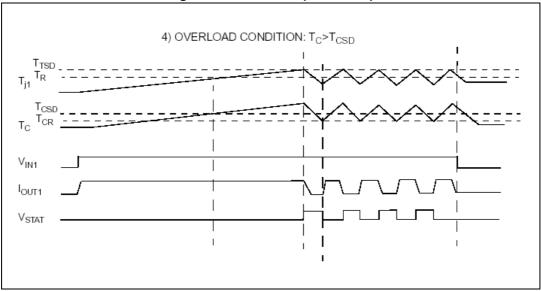


Figure 9. Waveforms (continued)

### 6 Reverse polarity protection

Reverse polarity protection can be implemented on board using two different solutions:

- Placing a resistor (R<sub>GND</sub>) between IC GND pin and load GND
- 2. Placing a diode between IC GND pin and load GND

If option 1 is selected, the minimum resistance value has to be selected according to the following equation:

#### **Equation 1**

where  $I_{GND}$  is the DC reverse ground pin current and can be found in *Section 1: Maximum ratings* of this datasheet.

Power dissipated by  $R_{GND}$  (when  $V_{CC} < 0$ : during reverse polarity situations) is:

#### **Equation 2**

$$P_D = (V_{CC})^2 / R_{GND}$$

If option 2 is selected, the diode has to be chosen by taking into account VRRM  $>|V_{cc}|$  and its power dissipation capability:

#### **Equation 3**

$$P_D \ge I_S^*V_f$$

Note:

In normal conditions (no reverse polarity) due to the diode, there is a voltage drop between GND of the device and GND of the system.

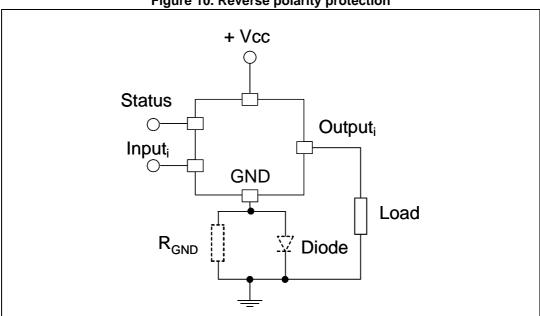


Figure 10. Reverse polarity protection

This schematic can be used with any type of load.

### 7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

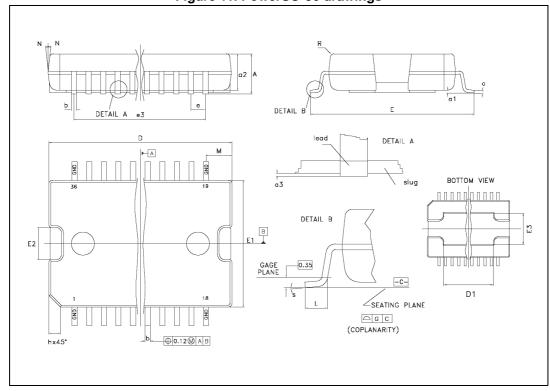


Figure 11. PowerSO-36 drawings

Table 10. PowerSO-36 mechanical data

Dim.	mm		
	Min.	Тур.	Max.
А			3.60
a1	0.10		0.30
a2			3.30
a3	0		0.10
b	0.22		0.38
С	0.23		0.32
D (1)	15.80		16.00
D1	9.40		9.80
Е	13.90		14.50
E1 (1)	10.90		11.10
E2			2.90
E3	5.8		6.2
е		0.65	
e3		11.05	
G	0		0.10
Н	15.50		15.90
h			1.10
L	0.80		1.10
N			10°
S	0°		8°



## 7.1 Footprint recommended data

B C A

Figure 12. Footprint recommended data

Table 11. Footprint data

Dim.	mm	
A	9.5	
В	14.7-15.0	
С	12.5-12.7	
D	6.3	
Е	0.42	
G	0.65	

## 7.2 Tube shipment information

H C C K

Figure 13. Tube shipment information

Table 12. Tube mechanical data

Dim.	mm
A	18.80
В	17.2 ±0.2
С	8.20 ±0.2
D	10.90 ±0.2
E	2.90 ±0.2
F	0.40
G	0.80
Н	6.30
I	4.30 ±0.2
J	3.7 ±0.2
К	9.4
L	0.40
M	0.80
N	3.50 ±0.2

Base quantity 31 pcs

Bulk quantity 310 pcs

### 7.3 Tape and reel shipment information

Tigale 14. Tape speciments

R BO

AO

Bending radius

User direction of feed

User direction of feed

Figure 14. Tape specifications

Table 13. Tape mechanical data

Dim.	mm	
D	1.50 +0.1/0	
E	1.75 ±0.1	
Po	4.00 ±0.1	
T max.	0.40	
D1 min.	1.50	
F	11.5 ±0.05	
K max.	6.50	
P2	2.00 ±0.1	
R	50	
W	24.00 ±0.30	
P1	24.00	
Ao, Bo, Ko	0.05 min. to 1.0 max.	

Base quantity 600 pcs Bulk quantity 600 pcs

18/22 DocID11455 Rev 12

40mm (1.575in) min. access hole at slot location С D Α G measured Full radius at hub Tape slot in core for tape start 2.5mm (0.098in) min. width

Figure 15. Reel specifications

Table 14. Reel mechanical data

Dim.	mm	
Tape size	24.0 ±0.30	
A max.	330.0	
B min.	1.5	
С	13.0 ±0.20	
D min.	20.2	
N min.	60	
G	24.4 +2/-0	
T max.	30.4	

Ordering information VN808-E

# 8 Ordering information

Table 15. Order code

Order code	Package	Packaging
VN808-E	PowerSO-36	Tube
VN808TR-E	PowerSO-36	Tape and reel

VN808-E Revision history

# 9 Revision history

**Table 16. Document revision history** 

Date	Revision	Changes
13-Sep-2005	1	Initial release
1-Mar-2007	2	Document reformatted
12-Mar-2007	3	Typo in Figure 3.
26-Mar-2007	4	Typo note <i>Table 2</i> .
07-Jul-2008	5	Added: Section 6 on page 13
04-Aug-2008	6	Added: Figure 12: Footprint recommended data on page 16
25-Aug-2009	7	Updated Section 6: Reverse polarity protection
24-Feb-2010	8	Updated Section 7: Package mechanical data
08-Nov-2012	9	Changed <i>Figure 5</i> .  Minor text changes to improve the readability.
19-Nov-2012	10	Added maximum value to I <sub>INL</sub> parameter in <i>Table 5</i> .
31-Jul-2013	11	Updated Section 7.1: Footprint recommended data.
18-Dec-2013	12	Replaced L <sub>MAX</sub> parameter by EAS parameter in <i>Table 1</i> .  Added T <sub>J</sub> condition to <i>Table 3</i> .  Updated <i>Section 6</i> .

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

ST PRODUCTS ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries. Information in this document supersedes and replaces all information previously supplied. The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

22/22 DocID11455 Rev 12



# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

 $\frac{ \mbox{STMicroelectronics}:}{\frac{\mbox{VN808-E}}{\mbox{VN808TR-E}}}$